

1. Features

- Reverse Working Voltage: 3.3V
- 350W Peak Pulse Power (8/20 μ s)
- IEC 61000-4-2 (ESD Air): \pm 30kV
IEC 61000-4-2 (ESD Contact): \pm 30kV
IEC 61000-4-5 (Lightning 8/20 μ s): 20A

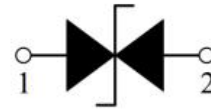
2. Pin Description



3. Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation

4. Schematic Diagram



5. Order Information

Type	Package	Size (mm)	Delivery Form	Delivery Quantity
SCSB11L450	SOD323	2.60x1.30x1.10	7" T&R	3,000

6. Limiting Values($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{ESD}	Electrostatic Discharge Voltage	IEC 61000-4-2; Contact Discharge	-	\pm 30	kV
		IEC 61000-4-2; Air Discharge	-	\pm 30	kV
P_{PP}	Peak Pulse Power	$t_p = 8/20\text{ }\mu\text{s}$	-	350	W
I_{PPM}	Rated Peak Pulse Current	$t_p = 8/20\text{ }\mu\text{s}$	-	20	A
T_{OP}	Operating Temperature Range	-	-55	125	$^{\circ}\text{C}$
T_{STRG}	Storage Temperature Range	-	-55	150	$^{\circ}\text{C}$

7. Electrical Characteristics($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
V_{RWM}	Reverse Working Voltage	$T_A = 25\text{ }^{\circ}\text{C}$	-	-	3.3	V
V_{BR}	Breakdown Voltage	$I_R = 1\text{ mA}$	4.0	-	-	V
I_R	Reverse Leakage Current	$V_{\text{RWM}} = 3.3\text{ V}$	-	-	0.5	μA
V_C	Clamping Voltage	$I_{\text{PP}} = 1\text{ A}$, $t_p = 8/20\text{ }\mu\text{s}$	-	7.5	-	V
		$I_{\text{PP}} = 20\text{ A}$, $t_p = 8/20\text{ }\mu\text{s}$	-	-	18.0	V
C_J	Junction Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	-	450	-	pF

8. Typical Characteristics

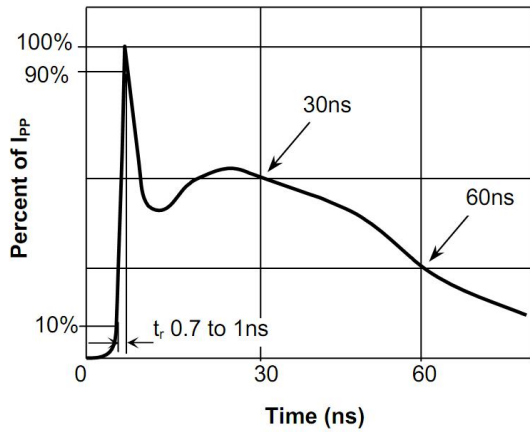


Fig.1 Pulse Waveform-ESD(IEC61000-4-2)

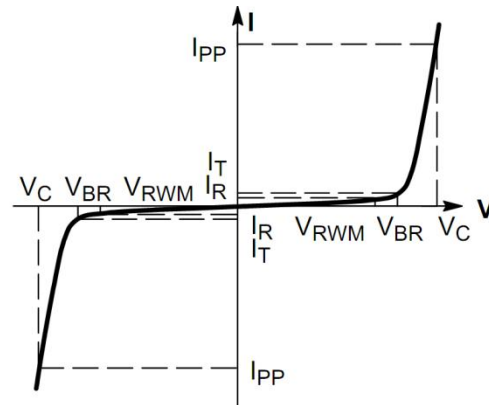


Fig.2 Pulse Derating Curve

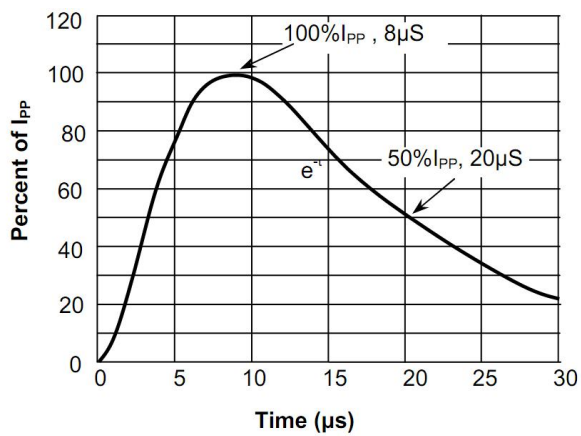


Fig.3 Pulse Waveform-8/20μs

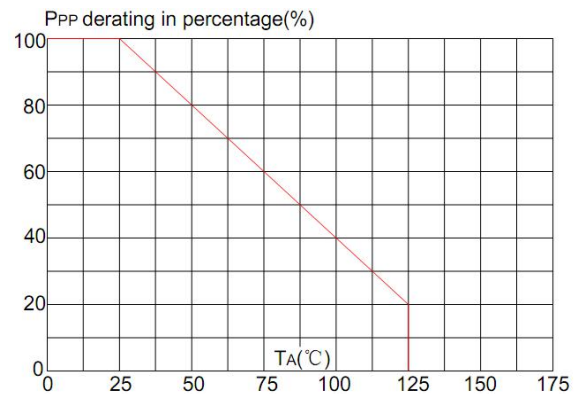
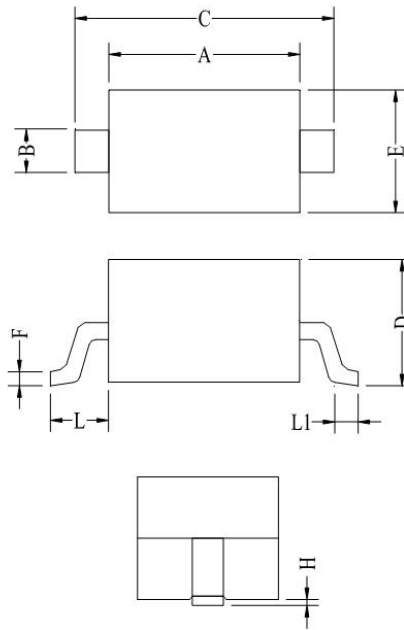


Fig.4 Pulse Derating Curve

9. Package Dimension

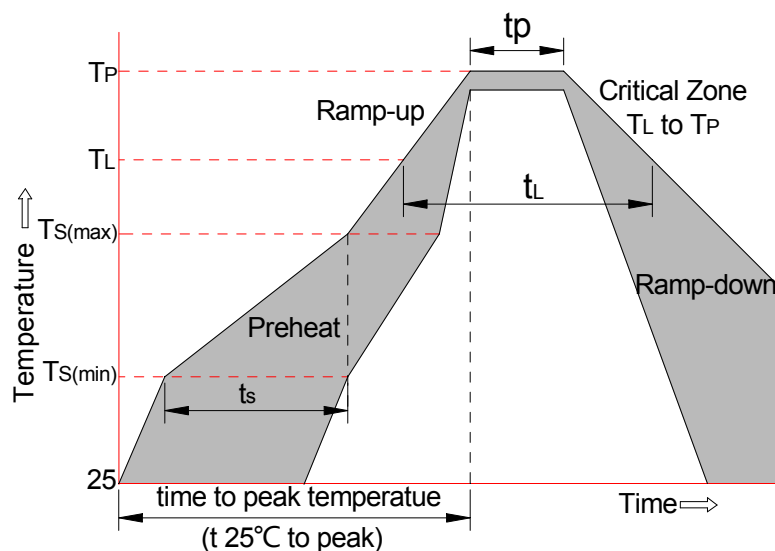
SOD323 Package Outline

Unit: millimeters



Symbol	Dimensions in millimeters	
	Min	Max
A	1.60	1.80
B	0.25	0.35
C	2.50	2.70
D	0.00	1.00
E	1.20	1.40
F	0.08	0.15
L	0.475REF	
L1	0.25	0.40
H	0.00	0.10

10. Soldering Parameters



Reflow Condition		Pb-Free Assembly
Pre-heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
xTime 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C